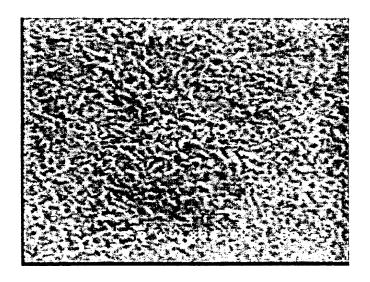
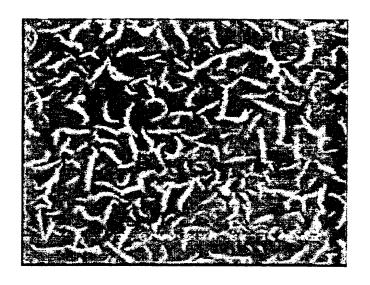


 $1 \mu m$

FIG. 8

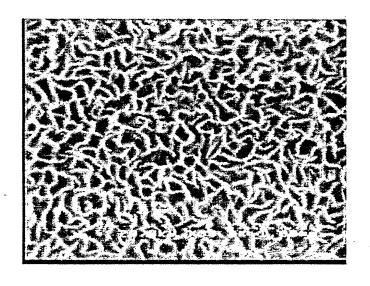


 $1 \mu m$

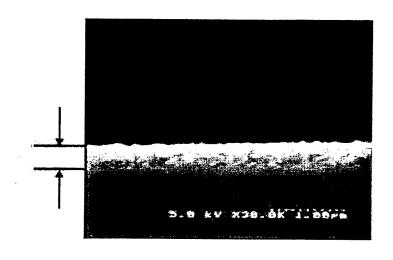


 $1 \mu m$

FIG. 10

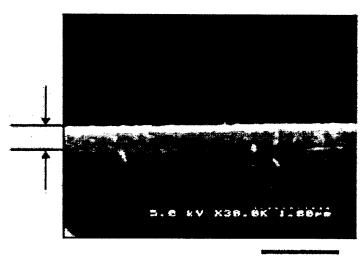


 $1 \mu m$

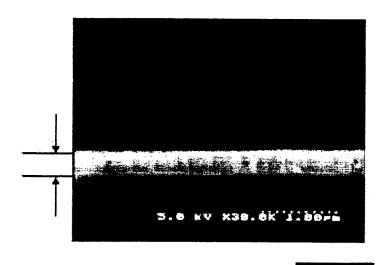


 $1 \mu m$

FIG. 12

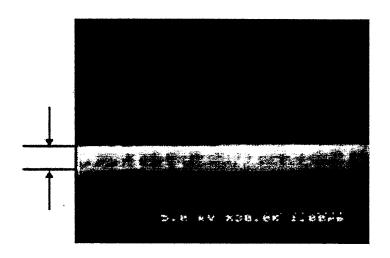


 $1 \mu \text{m}$



 $1 \mu m$

FIG. 14



 $1~\mu\,\mathrm{m}$

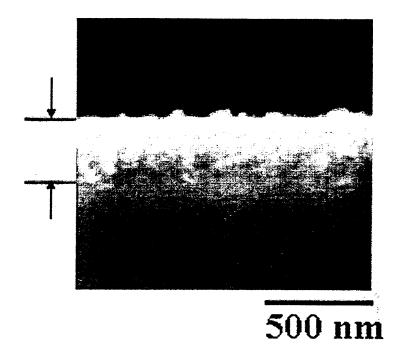
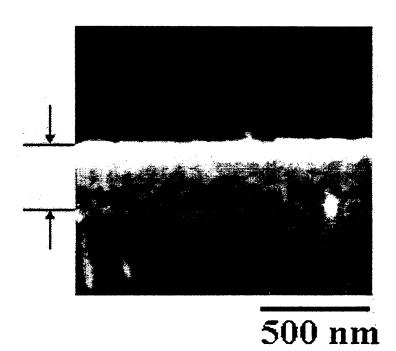
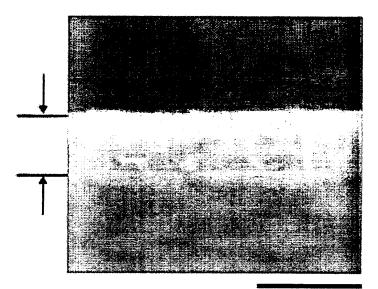


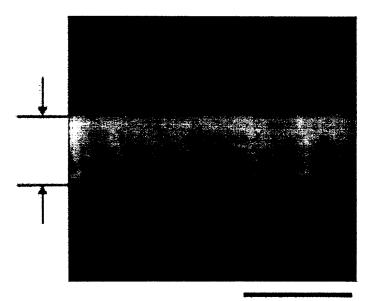
FIG. 16



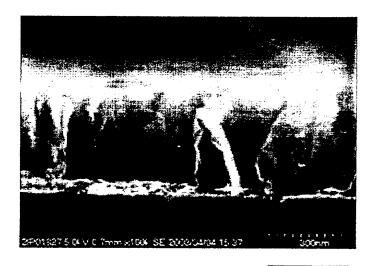


500 nm

FIG. 18

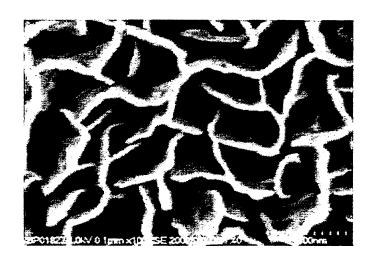


500 nm

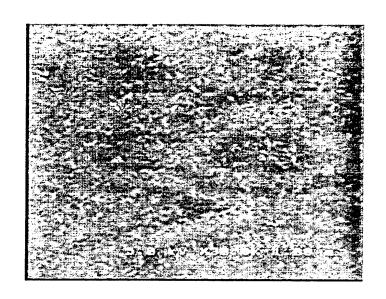


300 nm

FIG. 20

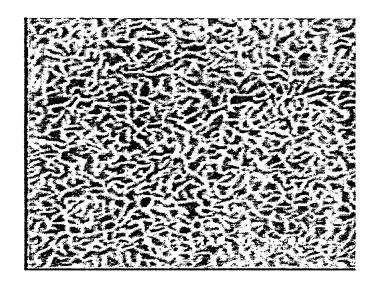


300 nm

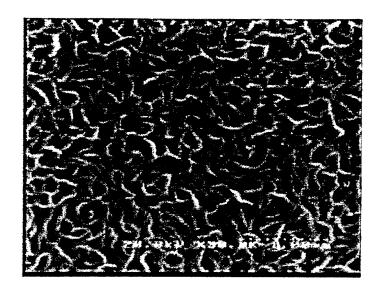


 $1 \mu m$

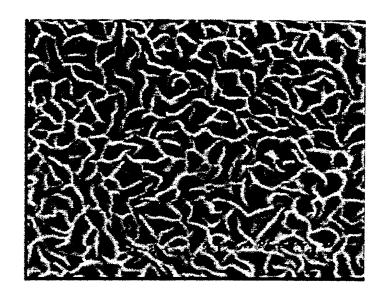
FIG. 22



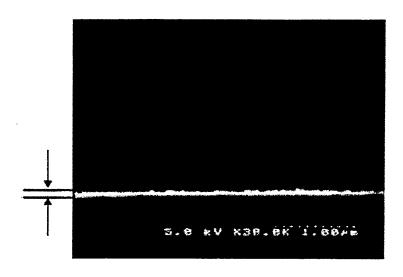
 $1 \mu m$



 $1 \mu m$

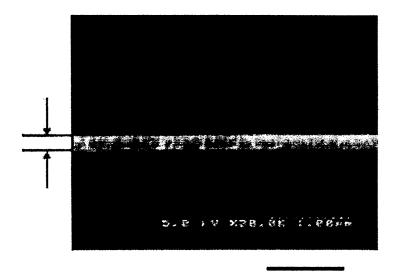


 $1 \mu m$

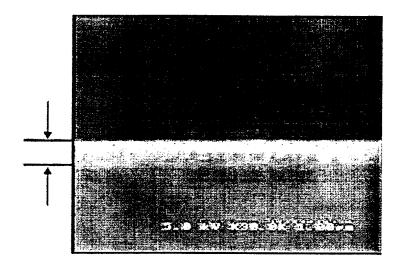


 $1 \mu m$

FIG. 26

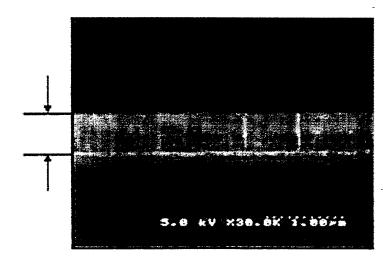


 $1 \mu m$



 $1 \mu m$

FIG. 28



1 μm

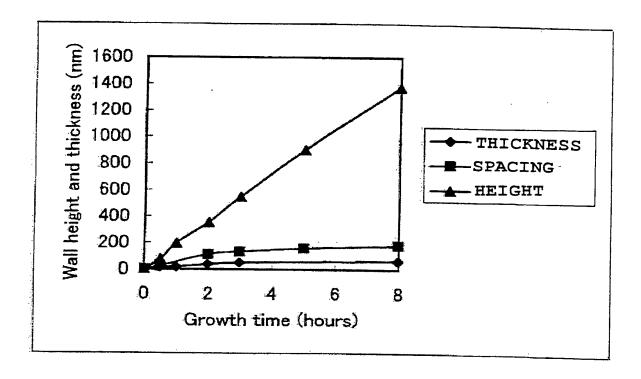
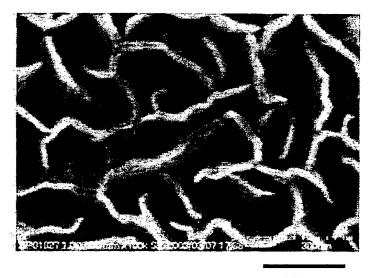
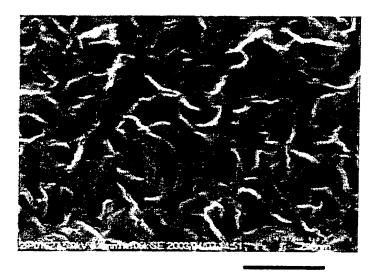


FIG. 30

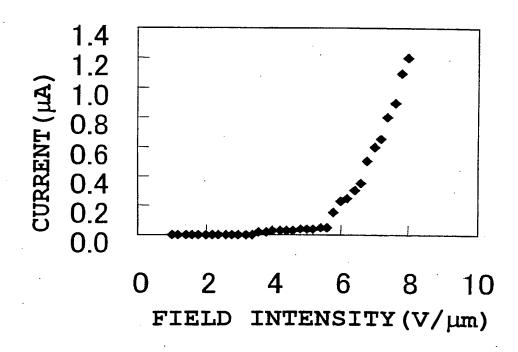


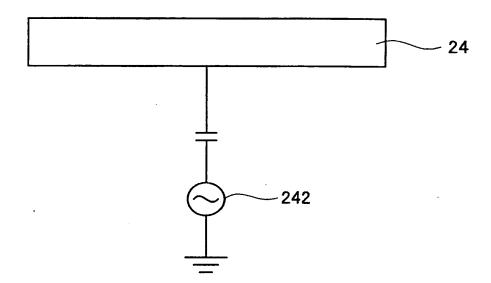
300 nm

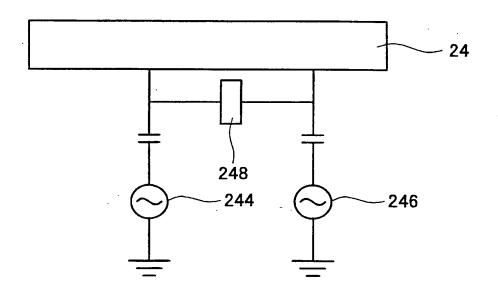


300 nm

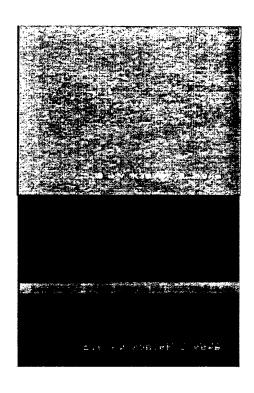
FIG. 32

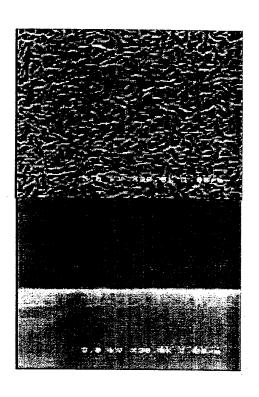






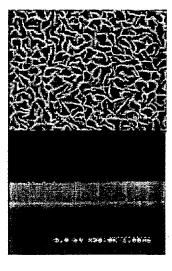
$C_2F_6/H_2(1)$

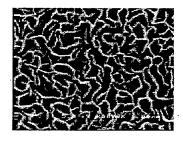


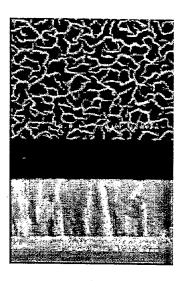


1 h 2 h

$C_2F_6/H_2(1)$



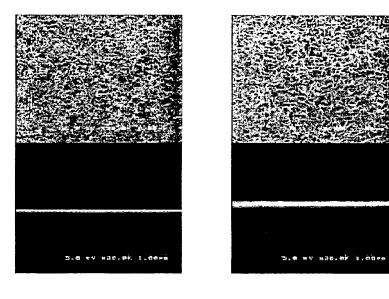


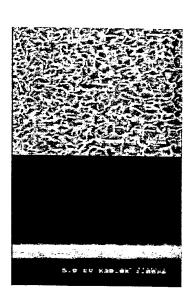


3 h

5 h

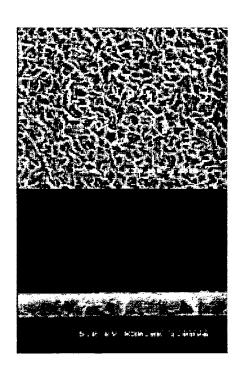
$CH_4/H_2(1)$



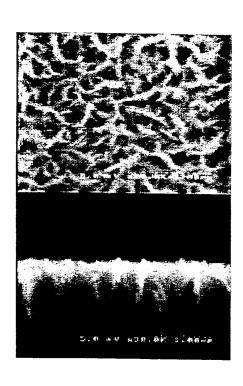


0.5 h 1 h 2 h

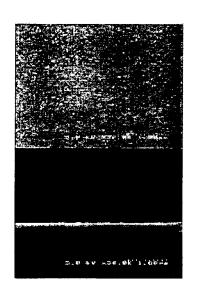
$CH_4/H_2(2)$

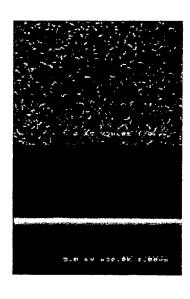


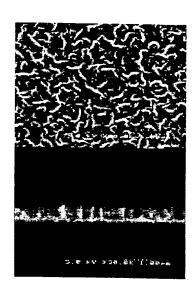
3 h



$CF_4/H_2(1)$



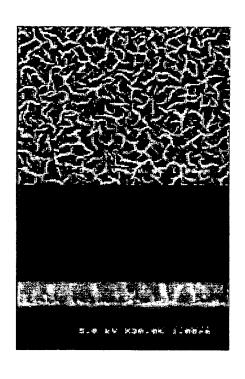


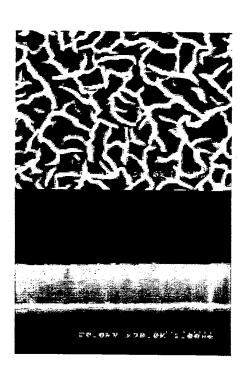


0.5 h

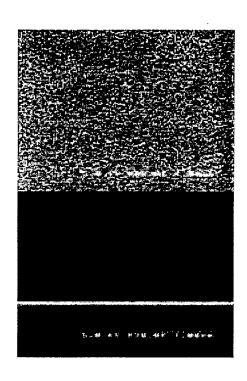
1 h

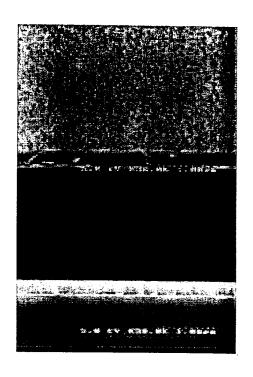
$CF_4/H_2(2)$





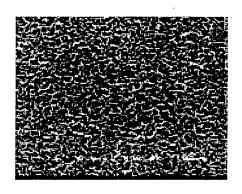
$\text{CHF}_3/\text{H}_2(1)$

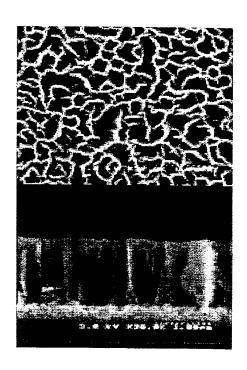




1 h 2 h

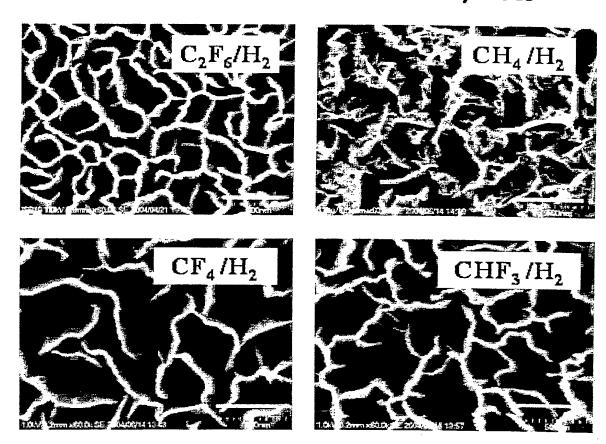
$CHF_{3}/H_{2}(2)$



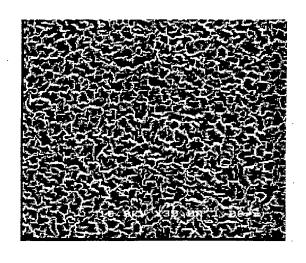


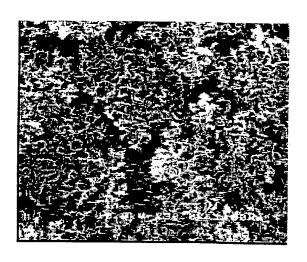
3 h 8 h

DIFFERENCE IN GAS (HIGH RESOLUTION SEM) -8h



DIFFERENCE IN SUBSTRATE (1)

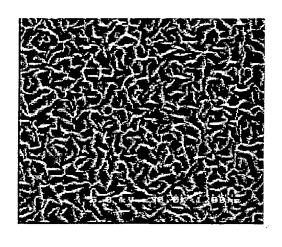


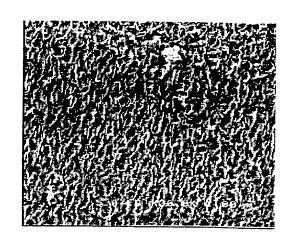


stainless steel

graphite

DIFFERENCE IN SUBSTRATE (2)





 SiO_2 Ni

DIFFERENCE IN CCP (C2F6)

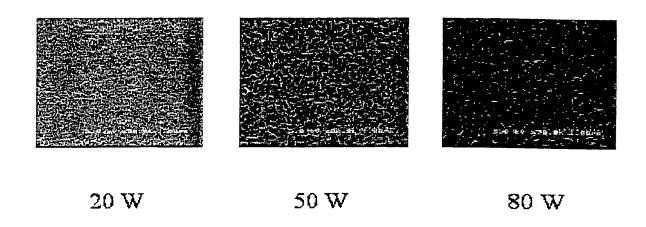
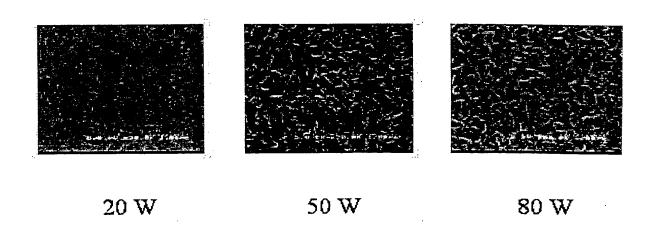
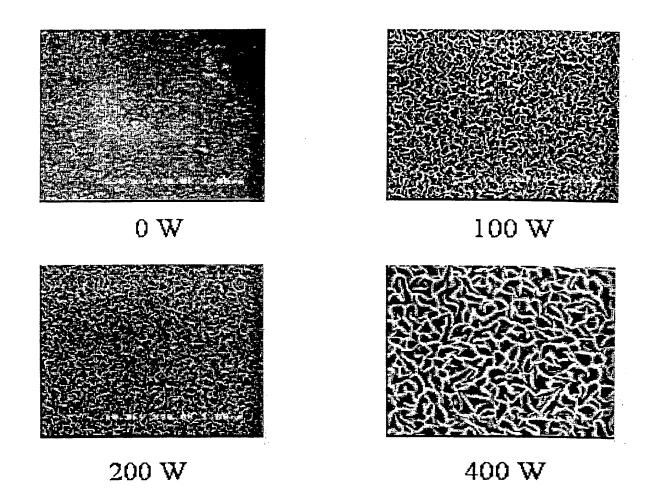


FIG. 47

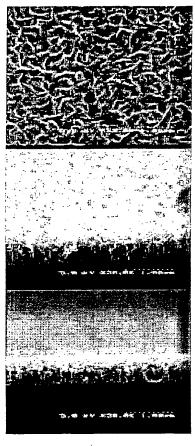
DIFFERENCE IN CCP (CH₄)



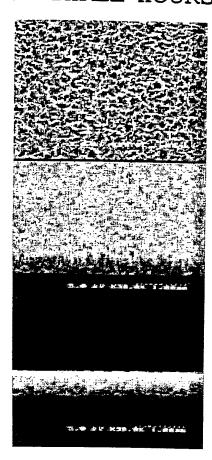
DIFFERENCE IN ICP (C2F6)



USE OF TWO DIFFERENT GASES (EACH USED FOR HALF OF A GROWTH TIME OF THREE HOURS)

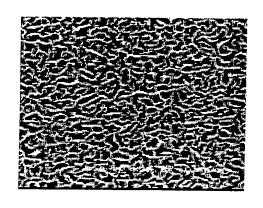


 $C_2F_6 \rightarrow CH_4$

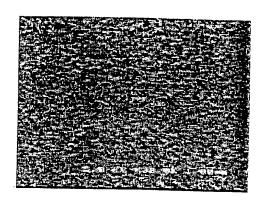


 $CH_4 \rightarrow C_2F_6$

DIFFERENCE IN FLOW RATE



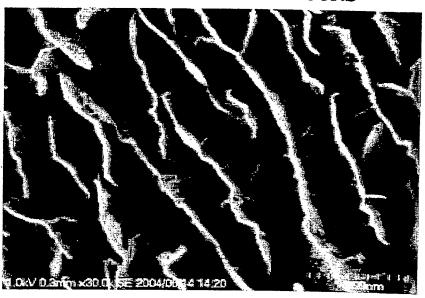
 $C_2F_6/H_2 = 7.5/30 \text{ secm}$



 $C_2F_6/H_2 = 24/24 \text{ secm}$

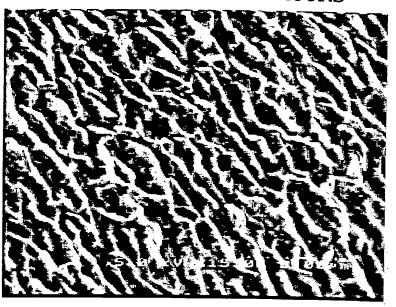
ORIENTATION

C₂F₆/H₂=20/80 CCP 100W,ICP 400W Si (100) SUBSTRATE SUBSTRATE TEMPERATURE OF 600°C GROWTH TIME OF EIGHT HOURS



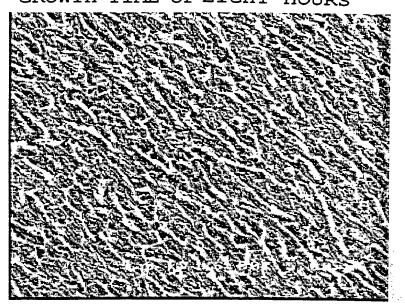
ORIENTATION

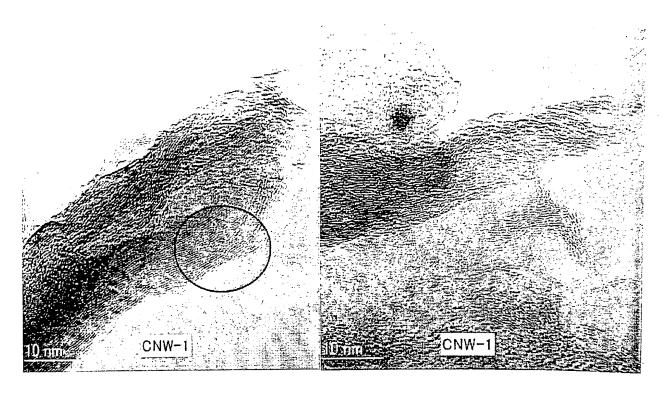
C₂F₆/H₂=20/80 CCP 100W, ICP 400W Si (100) SUBSTRATE SUBSTRATE TEMPERATURE OF 600°C GROWTH TIME OF EIGHT HOURS



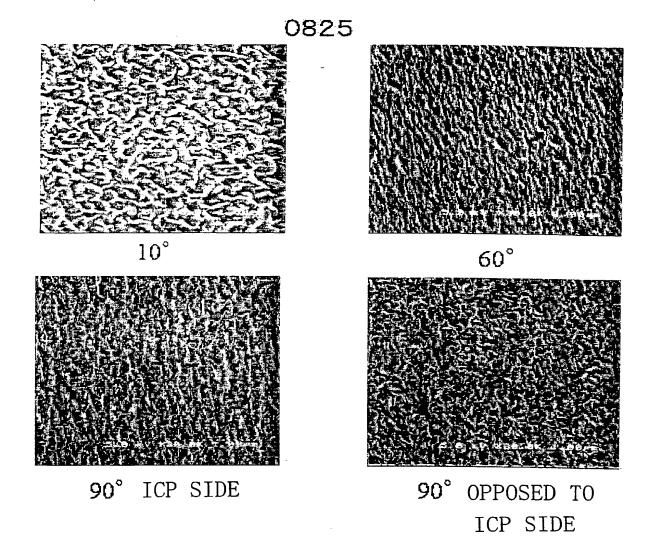
ORIENTATION

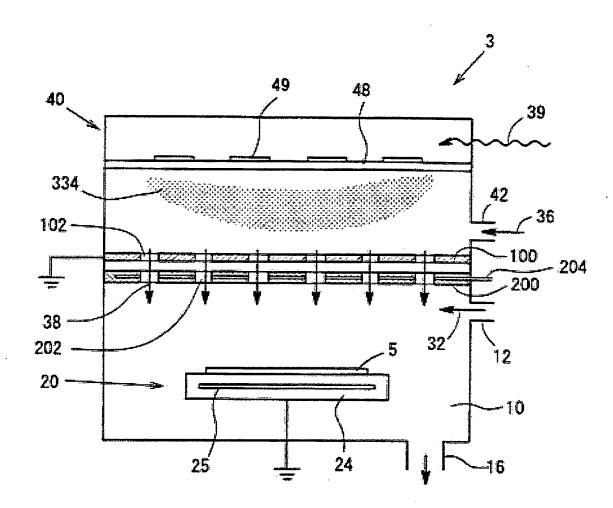
C₂F₆/H₂=20/80 CCP 100W, ICP 400W Si (100) SUBSTRATE SUBSTRATE TEMPERATURE OF 600°C GROWTH TIME OF EIGHT HOURS





MAGNIFICATION OF THREE HUNDRED THOUSAND





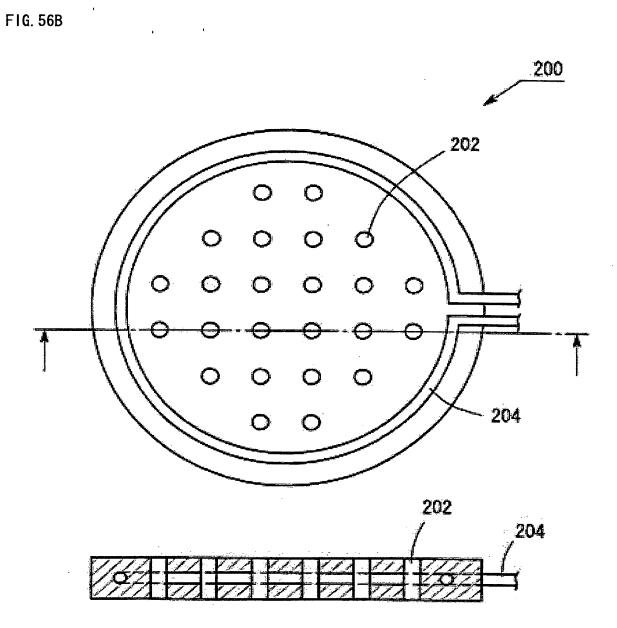
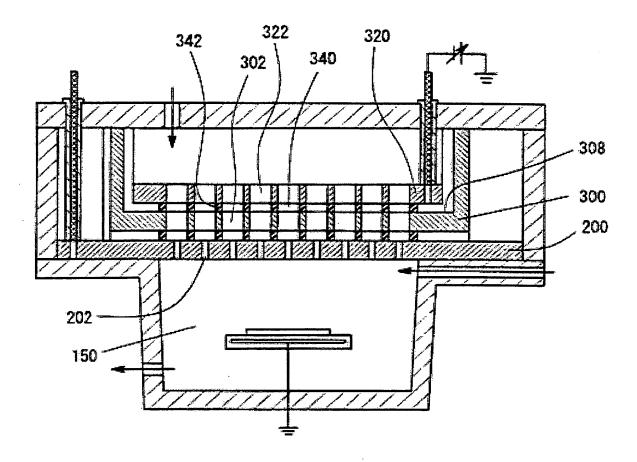
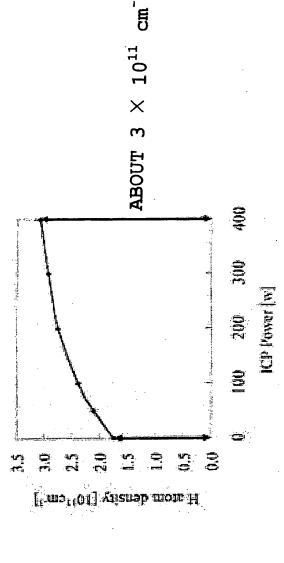


FIG. 57



CHANGE IN HYDROGEN ATOM DRNSITY DUE TO VARIATION ON (INDUCTIVELY COUPLED PLASMA OUTPUT OF 100W) OUTPUT OF INDUCTIVELY COUPLED PLASMA



ABOUT TWO TIMES DIFFERENCE BETWEEN ATOMIC DENSITIES

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